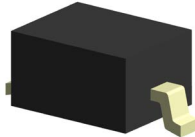


STS321XXXXXXAH

Automotive TVS diode ESD suppressor



Product features

- AEC-Q101
- Uni-directional and bi-directional options
- Protects one I/O line
- Low capacitance
- Meets moisture sensitivity level (MSL) 1
- Molding compound flammability rating: UL 94V-0

Applications

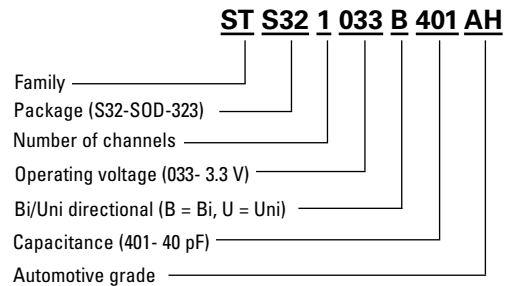
- Automotive chassis and safety systems
- Advanced driver assistance systems (ADAS)
- Communication and infotainment systems
- CAN-bus, LIN and Ethernet communication modules
- Network systems and body electronics
- Power train controls
- Automotive lighting

Environmental compliance and general specifications

- IEC61000-4-2 (ESD) Up to ± 30 kV (air), ± 30 kV (contact)
- IEC61000-4-4 (EFT) 40 A (5/50 ns)
- IEC61000-4-5 (Lightning) up to 35 A (8/20 μ s)



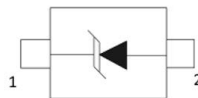
Ordering part number



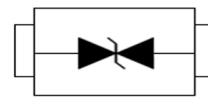
SOD-323



Pin configuration
Uni-directional



Pin configuration
Bi-directional



Product specifications

(+25 °C, RH=45%-75%, unless otherwise noted)

STS321033B401AH

Parameter	Test condition	Minimum	Typical	Maximum	Symbol (Units)
Peak pulse power dissipation	8/20 μ s waveform	-	350	-	P_{PP} (W)
ESD per IEC 61000-4-2 (Air)	-	-	+/-30	-	V_{ESD} (kV)
ESD per IEC 61000-4-2 (Contact)	-	-	+/-30	-	V_{ESD} (kV)
Lead soldering temperature	-	-	+260 (10 seconds)	-	T_L ($^{\circ}$ C)
Operating junction temperature range	-	-55	-	+150	T_J ($^{\circ}$ C)
Storage temperature range	-	-55	-	+150	T_{STG} ($^{\circ}$ C)
Reverse working voltage	-	-	-	3.3	V_{RWM} (V)
Reverse breakdown voltage	$I_T = 1$ mA	3.6	-	-	V_{BR} (V)
Reverse leakage current	$V_{RWM} = 3.3$ V	-	-	1	I_R (μ A)
Clamping voltage	$I_{PP} = 30$ A, $t_p = 8/20$ μ s	-	-	15	V_C (V)
Junction capacitance	$V_{RWM} = 0$ V, $f = 1$ MHz	-	40	80	C_J (pF)

STS321033U202AH

Parameter	Test condition	Minimum	Typical	Maximum	Symbol (Units)
Peak pulse power dissipation	8/20 μ s waveform	-	350	-	P_{PP} (W)
ESD per IEC 61000-4-2 (Air)	-	-	+/-30	-	V_{ESD} (kV)
ESD per IEC 61000-4-2 (Contact)	-	-	+/-30	-	V_{ESD} (kV)
Lead soldering temperature	-	-	+260 (10 seconds)	-	T_L ($^{\circ}$ C)
Operating junction temperature range	-	-55	-	+150	T_J ($^{\circ}$ C)
Storage temperature range	-	-55	-	+150	T_{STG} ($^{\circ}$ C)
Reverse working voltage	-	-	-	3.3	V_{RWM} (V)
Reverse breakdown voltage	$I_T = 1$ mA	4	-	-	V_{BR} (V)
Reverse leakage current	$V_{RWM} = 3.3$ V	-	1	5	I_R (μ A)
Clamping voltage	$I_{PP} = 1$ A, $t_p = 8/20$ μ s	-	5.5	6.5	V_C (V)
	$I_{PP} = 25$ A, $t_p = 8/20$ μ s	-	10	15	V_C (V)
Junction capacitance	$V_{RWM} = 0$ V, $f = 1$ MHz	-	200	250	C_J (pF)

STS321050B331AH

Parameter	Test condition	Minimum	Typical	Maximum	Symbol (Units)
Peak pulse power dissipation	8/20 μ s waveform	-	400	-	P_{PP} (W)
ESD per IEC 61000-4-2 (Air)	-	-	+/-30	-	V_{ESD} (kV)
ESD per IEC 61000-4-2 (Contact)	-	-	+/-30	-	V_{ESD} (kV)
Lead soldering temperature	-	-	+260 (10 seconds)	-	T_L ($^{\circ}$ C)
Operating junction temperature range	-	-55	-	+150	T_J ($^{\circ}$ C)
Storage temperature range	-	-55	-	+150	T_{STG} ($^{\circ}$ C)
Reverse working voltage	-	-	-	5.0	V_{RWM} (V)
Reverse breakdown voltage	$I_T = 1$ mA	5.5	-	-	V_{BR} (V)
Reverse leakage current	$V_{RWM} = 5$ V	-	-	1.0	I_R (μ A)
Clamping voltage	$I_{PP} = 1$ A, $t_p = 8/20$ μ s	-	6.5	9	V_C (V)
	$I_{PP} = 35$ A, $t_p = 8/20$ μ s	-	10.5	14	V_C (V)
Junction capacitance	$V_{RWM} = 0$ V, $f = 1$ MHz	-	-	80	C_J (pF)

STS321050U182AH

Parameter	Test condition	Minimum	Typical	Maximum	Symbol (Units)
Peak pulse power dissipation	8/20 μ s waveform	-	350	-	P_{PP} (W)
ESD per IEC 61000-4-2 (Air)	-	-	+/-30	-	V_{ESD} (kV)
ESD per IEC 61000-4-2 (Contact)	-	-	+/-30	-	V_{ESD} (kV)
Lead soldering temperature	-	-	+260 (10 seconds)	-	T_L ($^{\circ}$ C)
Operating junction temperature range	-	-55	-	+150	T_J ($^{\circ}$ C)
Storage temperature range	-	-55	-	+150	T_{STG} ($^{\circ}$ C)
Reverse working voltage	-	-	-	5	V_{RWM} (V)
Reverse breakdown voltage	$I_T = 1$ mA	6	-	-	V_{BR} (V)
Reverse leakage current	$V_{RWM} = 5$ V	-	-	1.0	I_R (μ A)
Clamping voltage	$I_{PP} = 1$ A, $t_p = 8/20$ μ s	-	-	9	V_C (V)
	$I_{PP} = 22$ A, $t_p = 8/20$ μ s	-	12	15	V_C (V)
Junction capacitance	$V_{RWM} = 0$ V, $f = 1$ MHz	-	180	-	C_J (pF)

STS321070U162AH

Parameter	Test condition	Minimum	Typical	Maximum	Symbol (Units)
Peak pulse power dissipation	8/20 μ s waveform	-	350	-	P_{PP} (W)
ESD per IEC 61000-4-2 (Air)	-	-	+/-30	-	V_{ESD} (kV)
ESD per IEC 61000-4-2 (Contact)	-	-	+/-30	-	V_{ESD} (kV)
Lead soldering temperature	-	-	+260 (10 seconds)	-	T_L ($^{\circ}$ C)
Operating junction temperature range	-	-55	-	+150	T_J ($^{\circ}$ C)
Storage temperature range	-	-55	-	+150	T_{STG} ($^{\circ}$ C)
Reverse working voltage	-	-	-	7	V_{RWM} (V)
Reverse breakdown voltage	$I_T = 1$ mA	7.5	8.5	9	V_{BR} (V)
Reverse leakage current	$V_{RWM} = 7$ V	-	0.1	0.5	I_R (μ A)
Clamping voltage	$I_{PP} = 1$ A, $t_p = 8/20$ μ s	-	11.5	15	V_C (V)
	$I_{PP} = 25$ A, $t_p = 8/20$ μ s	-	15.5	20	V_C (V)
Junction capacitance	$V_{RWM} = 0$ V, $f = 1$ MHz	-	165	200	C_J (pF)

STS321120B301AH

Parameter	Test condition	Minimum	Typical	Maximum	Symbol (Units)
Peak pulse power dissipation	8/20 μ s waveform	-	400	-	P_{PP} (W)
ESD per IEC 61000-4-2 (Air)	-	-	+/-30	-	V_{ESD} (kV)
ESD per IEC 61000-4-2 (Contact)	-	-	+/-30	-	V_{ESD} (kV)
Lead soldering temperature	-	-	+260 (10 seconds)	-	T_L ($^{\circ}$ C)
Operating junction temperature range	-	-55	-	+150	T_J ($^{\circ}$ C)
Storage temperature range	-	-55	-	+150	T_{STG} ($^{\circ}$ C)
Reverse working voltage	-	-	-	12	V_{RWM} (V)
Reverse breakdown voltage	$I_T = 1$ mA	13.3	-	-	V_{BR} (V)
Reverse leakage current	$V_{RWM} = 12$ V	-	-	1.0	I_R (μ A)
Clamping voltage	$I_{PP} = 1$ A, $t_p = 8/20$ μ s	-	-	19	V_C (V)
	$I_{PP} = 12$ A, $t_p = 8/20$ μ s	-	-	33	V_C (V)
Junction capacitance	$V_{RWM} = 0$ V, $f = 1$ MHz	-	30	45	C_J (pF)

STS321120U901AH

Parameter	Test condition	Minimum	Typical	Maximum	Symbol (Units)
Peak pulse power dissipation	8/20 μ s waveform	-	350	-	P_{pp} (W)
ESD per IEC 61000-4-2 (Air)	-	-	+/-30	-	V_{ESD} (kV)
ESD per IEC 61000-4-2 (Contact)	-	-	+/-30	-	V_{ESD} (kV)
Lead soldering temperature	-	-	+260 (10 seconds)	-	T_L ($^{\circ}$ C)
Operating junction temperature range	-	-55	-	+150	T_J ($^{\circ}$ C)
Storage temperature range	-	-55	-	+150	T_{STG} ($^{\circ}$ C)
Reverse working voltage	-	-	-	12	V_{RWM} (V)
Reverse breakdown voltage	$I_T = 1$ mA	13.3	13.5	16	V_{BR} (V)
Reverse leakage current	$V_{RWM} = 12$ V	-	0.01	0.1	I_R (μ A)
Clamping voltage	$I_{pp} = 1$ A, $t_p = 8/20$ μ s	-	15	18	V_C (V)
	$I_{pp} = 15$ A, $t_p = 8/20$ μ s	-	21	24	V_C (V)
Junction capacitance	$V_{RWM} = 0$ V, $f = 1$ MHz	-	90	100	C_J (pF)

STS321150B351AH

Parameter	Test condition	Minimum	Typical	Maximum	Symbol (Units)
Peak pulse power dissipation	8/20 μ s waveform	-	400	-	P_{pp} (W)
ESD per IEC 61000-4-2 (Air)	-	-	+/-30	-	V_{ESD} (kV)
ESD per IEC 61000-4-2 (Contact)	-	-	+/-30	-	V_{ESD} (kV)
Lead soldering temperature	-	-	+260 (10 seconds)	-	T_L ($^{\circ}$ C)
Operating junction temperature range	-	-55	-	+150	T_J ($^{\circ}$ C)
Storage temperature range	-	-55	-	+150	T_{STG} ($^{\circ}$ C)
Reverse working voltage	-	-	-	15	V_{RWM} (V)
Reverse breakdown voltage	$I_T = 1$ mA	16.7	-	-	V_{BR} (V)
Reverse leakage current	$V_{RWM} = 15$ V	-	-	1	I_R (μ A)
Clamping voltage	$I_{pp} = 1$ A, $t_p = 8/20$ μ s	-	-	23	V_C (V)
	$I_{pp} = 10$ A, $t_p = 8/20$ μ s	-	-	33	V_C (V)
Junction capacitance	$V_{RWM} = 0$ V, $f = 1$ MHz	-	35	40	C_J (pF)

STS321150U751AH

Parameter	Test condition	Minimum	Typical	Maximum	Symbol (Units)
Peak pulse power dissipation	8/20 μ s waveform	-	350	-	P_{pp} (W)
ESD per IEC 61000-4-2 (Air)	-	-	+/-30	-	V_{ESD} (kV)
ESD per IEC 61000-4-2 (Contact)	-	-	+/-25	-	V_{ESD} (kV)
Lead soldering temperature	-	-	+260 (10 seconds)	-	T_L ($^{\circ}$ C)
Operating junction temperature range	-	-55	-	+150	T_J ($^{\circ}$ C)
Storage temperature range	-	-55	-	+150	T_{STG} ($^{\circ}$ C)
Reverse working voltage	-	-	-	15	V_{RWM} (V)
Reverse breakdown voltage	$I_T = 1$ mA	16	17	19	V_{BR} (V)
Reverse leakage current	$V_{RWM} = 15$ V	-	0.1	0.2	I_R (μ A)
Clamping voltage	$I_{pp} = 1$ A, $t_p = 8/20$ μ s	-	20	23	V_C (V)
	$I_{pp} = 13$ A, $t_p = 8/20$ μ s	-	27	30	V_C (V)
Junction capacitance	$V_{RWM} = 0$ V, $f = 1$ MHz	-	75	90	C_J (pF)

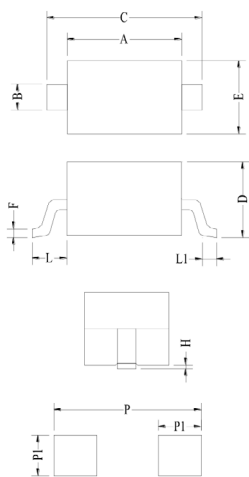
STS321240B301AH					
Parameter	Test condition	Minimum	Typical	Maximum	Symbol (Units)
Peak pulse power dissipation	8/20 μ s waveform	-	400	-	P_{PP} (W)
ESD per IEC 61000-4-2 (Air)	-	-	+/-30	-	V_{ESD} (kV)
ESD per IEC 61000-4-2 (Contact)	-	-	+/-30	-	V_{ESD} (kV)
Lead soldering temperature	-	-	+260 (10 seconds)	-	T_L ($^{\circ}$ C)
Operating junction temperature range	-	-55	-	+150	T_J ($^{\circ}$ C)
Storage temperature range	-	-55	-	+150	T_{STG} ($^{\circ}$ C)
Reverse working voltage	-	-	-	24	V_{RWM} (V)
Reverse breakdown voltage	$I_T = 1$ mA	26.7	-	-	V_{BR} (V)
Reverse leakage current	$V_{RWM} = 24$ V	-	-	1.0	I_R (μ A)
Clamping voltage	$I_{PP} = 1$ A, $t_p = 8/20$ μ s	-	-	40	V_C (V)
	$I_{PP} = 8$ A, $t_p = 8/20$ μ s	-	-	50	V_C (V)
Junction capacitance	$V_{RWM} = 0$ V, $f = 1$ MHz	-	30	35	C_J (pF)

STS321240U401AH					
Parameter	Test condition	Minimum	Typical	Maximum	Symbol (Units)
Peak pulse power dissipation	8/20 μ s waveform	-	350	-	P_{PP} (W)
ESD per IEC 61000-4-2 (Air)	-	-	+/-30	-	V_{ESD} (kV)
ESD per IEC 61000-4-2 (Contact)	-	-	+/-30	-	V_{ESD} (kV)
Lead soldering temperature	-	-	+260 (10 seconds)	-	T_L ($^{\circ}$ C)
Operating junction temperature range	-	-55	-	+150	T_J ($^{\circ}$ C)
Storage temperature range	-	-55	-	+150	T_{STG} ($^{\circ}$ C)
Reverse working voltage	-	-	-	24	V_{RWM} (V)
Reverse breakdown voltage	$I_T = 1$ mA	26.4	28	32	V_{BR} (V)
Reverse leakage current	$V_{RWM} = 24$ V	-	-	0.1	I_R (μ A)
Clamping voltage	$I_{PP} = 1$ A, $t_p = 8/20$ μ s	-	-	36	V_C (V)
	$I_{PP} = 8$ A, $t_p = 8/20$ μ s	-	-	45	V_C (V)
Junction capacitance	$V_{RWM} = 0$ V, $f = 1$ MHz	-	40	70	C_J (pF)

STS321360B141AH					
Parameter	Test condition	Minimum	Typical	Maximum	Symbol (Units)
Peak pulse power dissipation	8/20 μ s waveform	-	400	-	P_{PP} (W)
ESD per IEC 61000-4-2 (Air)	-	-	+/-30	-	V_{ESD} (kV)
ESD per IEC 61000-4-2 (Contact)	-	-	+/-30	-	V_{ESD} (kV)
Lead soldering temperature	-	-	+260 (10 seconds)	-	T_L ($^{\circ}$ C)
Operating junction temperature range	-	-55	-	+150	T_J ($^{\circ}$ C)
Storage temperature range	-	-55	-	+150	T_{STG} ($^{\circ}$ C)
Reverse working voltage	-	-	-	36	V_{RWM} (V)
Reverse breakdown voltage	$I_T = 1$ mA	40	42	47.5	V_{BR} (V)
Reverse leakage current	$V_{RWM} = 36$ V	-	-	0.2	I_R (μ A)
Clamping voltage	$I_{PP} = 1$ A, $t_p = 8/20$ μ s	-	45	60	V_C (V)
		$I_{PP} = 6$ A, $t_p = 8/20$ μ s	-	60	70
Junction capacitance	$V_{RWM} = 0$ V, $f = 1$ MHz	-	14	25	C_J (pF)

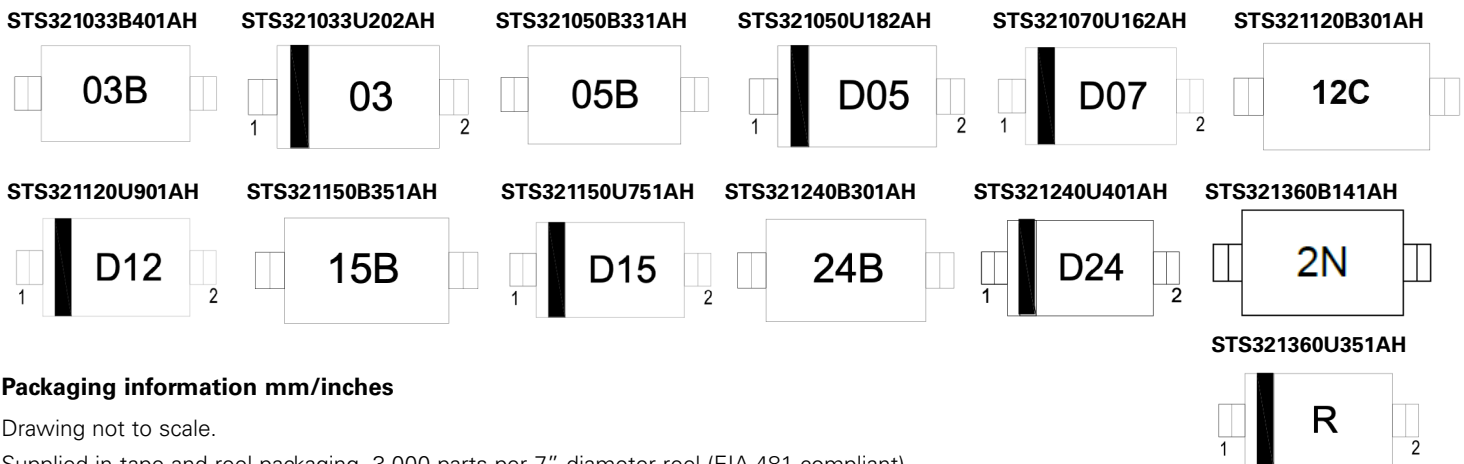
STS321360U351AH					
Parameter	Test condition	Minimum	Typical	Maximum	Symbol (Units)
Peak pulse power dissipation	8/20 μ s waveform	-	500	-	P_{PP} (W)
ESD per IEC 61000-4-2 (Air)	-	-	+/-15	-	V_{ESD} (kV)
ESD per IEC 61000-4-2 (Contact)	-	-	+/-8	-	V_{ESD} (kV)
Lead soldering temperature	-	-	+260 (10 seconds)	-	T_L ($^{\circ}$ C)
Operating junction temperature range	-	-55	-	+150	T_J ($^{\circ}$ C)
Storage temperature range	-	-55	-	+150	T_{STG} ($^{\circ}$ C)
Reverse working voltage	-	-	-	36	V_{RWM} (V)
Reverse breakdown voltage	$I_T = 1$ mA	39	-	-	V_{BR} (V)
Reverse leakage current	$V_{RWM} = 36$ V	-	-	0.1	I_R (μ A)
Clamping voltage	$I_{PP} = 1$ A, $t_p = 8/20$ μ s	-	45	55	V_C (V)
		$I_{PP} = 6$ A, $t_p = 8/20$ μ s	-	60	65
Junction capacitance	$V_{RWM} = 0$ V, $f = 1$ MHz	-	35	45	C_J (pF)

Mechanical parameters, pad layout- mm/inches



Dimension	Millimeters			Inches		
	Minimum	Typical	Maximum	Minimum	Typical	Maximum
A	1.6	1.7	1.8	0.063	0.067	0.071
B	0.25	0.32	0.4	0.010	0.013	0.016
C	2.3	2.6	2.8	0.091	0.102	0.11
D	0.8	0.95	1.1	0.031	0.037	0.043
E	1.2	1.3	1.4	0.047	0.051	0.055
F	0.08	0.13	0.18	0.003	0.005	0.007
L	-	0.475 ref	-	-	0.019 ref	-
L1	0.25	0.33	0.4	0.01	0.013	0.016
H	-	0.06	0.14	-	0.002	0.006
P	-	3.00	-	-	0.118	-
P1	-	0.80	-	-	0.031	-

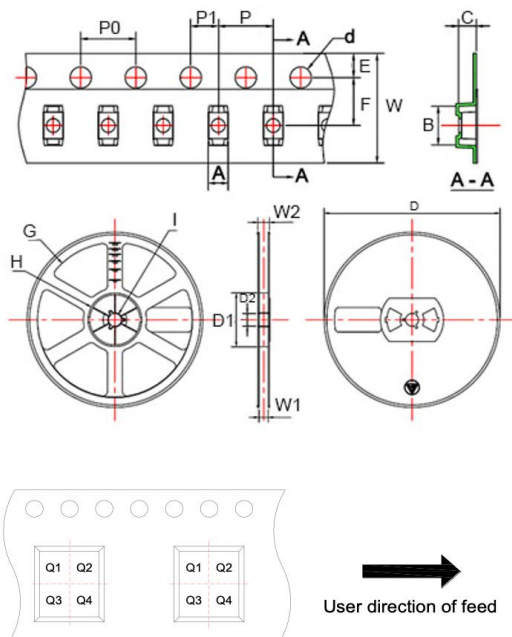
Marking code



Packaging information mm/inches

Drawing not to scale.

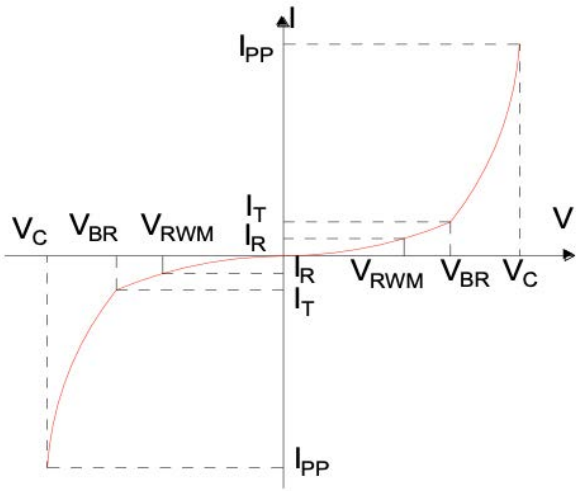
Supplied in tape and reel packaging, 3,000 parts per 7" diameter reel (EIA-481 compliant)



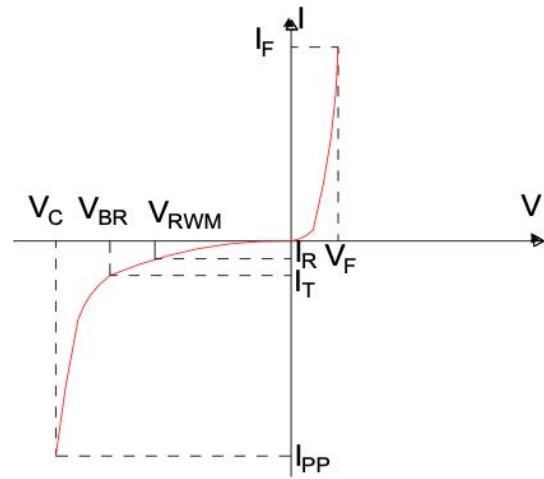
Dimension	Millimeter (typical)	Inches (typical)
A	1.46	0.057
B	2.9	0.114
C	1.25	0.049
d	1.50	0.059
E	1.75	0.069
F	3.5	0.138
P0	4	0.157
P	4	0.157
P1	2	0.079
W	8	0.315
D	178.0	7.008
D1	54.4	2.142
D2	13	0.512
G	R78.0	R3.071
H	R25.60	R1.008
I	R6.50	R0.256
W1	9.5	0.374
W2	12.3	0.484

Ratings and V-I characteristic curves (+25 °C unless otherwise noted)

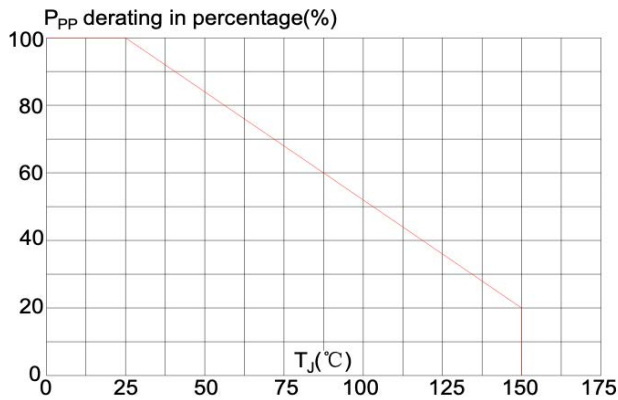
V- I curve characteristics (Bi-directional)



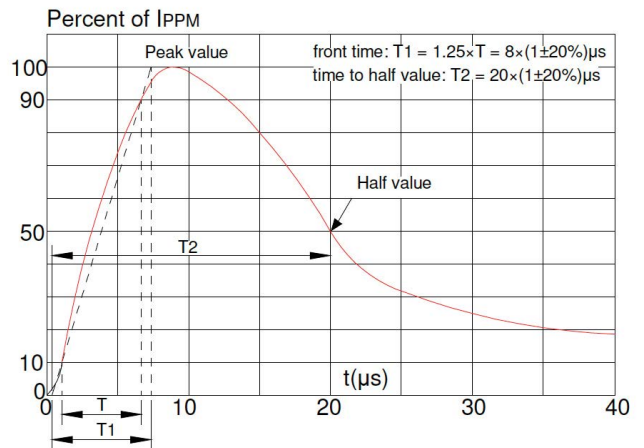
V- I curve characteristics (Uni-directional)



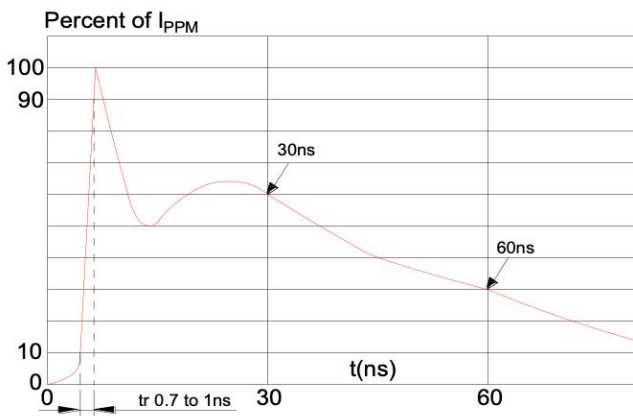
Pulse derating curve



Pulse waveform (8/20 μs)



ESD waveform (30 kV contact)



Solder reflow profile

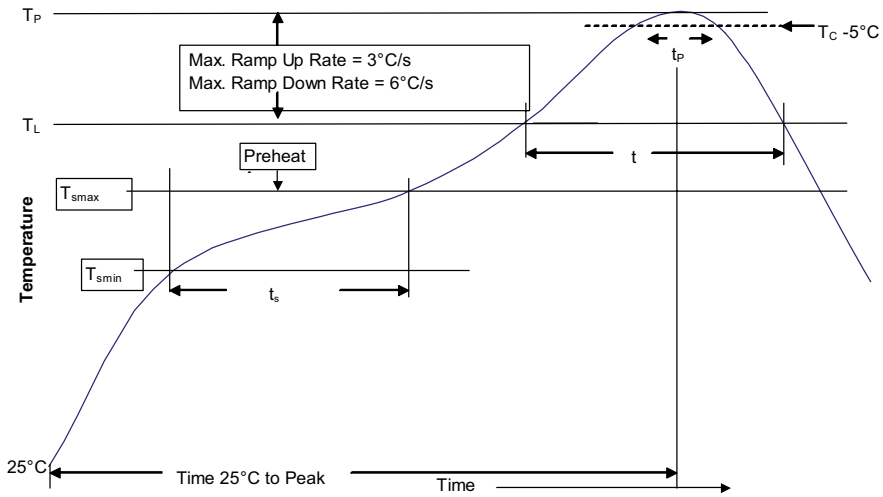


Table 1 - Standard SnPb solder (T_C)

Package thickness	Volume mm ³ <350	Volume mm ³ ≥350
<2.5 mm	235 °C	220 °C
≥2.5 mm	220 °C	220 °C

Table 2 - Lead (Pb) free solder (T_C)

Package thickness	Volume mm ³ <350	Volume mm ³ 350 - 2000	Volume mm ³ >2000
<1.6 mm	260 °C	260 °C	260 °C
1.6 – 2.5 mm	260 °C	250 °C	245 °C
>2.5 mm	250 °C	245 °C	245 °C

Reference J-STD-020

Profile feature	Standard SnPb solder	Lead (Pb) free solder
Preheat and soak		
• Temperature min. (T _{smin})	100 °C	150 °C
• Temperature max. (T _{smax})	150 °C	200 °C
• Time (T _{smin} to T _{smax}) (t _s)	60-120 seconds	60-120 seconds
Ramp up rate T _L to T _p	3 °C/ second max.	3 °C/ second max.
Liquidous temperature (T _L)	183 °C	217 °C
Time (t _L) maintained above T _L	60-150 seconds	60-150 seconds
Peak package body temperature (T _p)*	Table 1	Table 2
Time (t _p)* within 5 °C of the specified classification temperature (T _C)	20 seconds*	30 seconds*
Ramp-down rate (T _p to T _L)	6 °C/ second max.	6 °C/ second max.
Time 25 °C to peak temperature	6 minutes max.	8 minutes max.

* Tolerance for peak profile temperature (T_p) is defined as a supplier minimum and a user maximum.

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